

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceed the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-35835
 - Class Q Military
 - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)

• Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

4-Wide OR-AND/OR-AND Gate

The MC10121 is a basic logic building block providing the simultaneous OR–AND/OR–AND–Invert function, useful in data control and digital multiplexing applications.

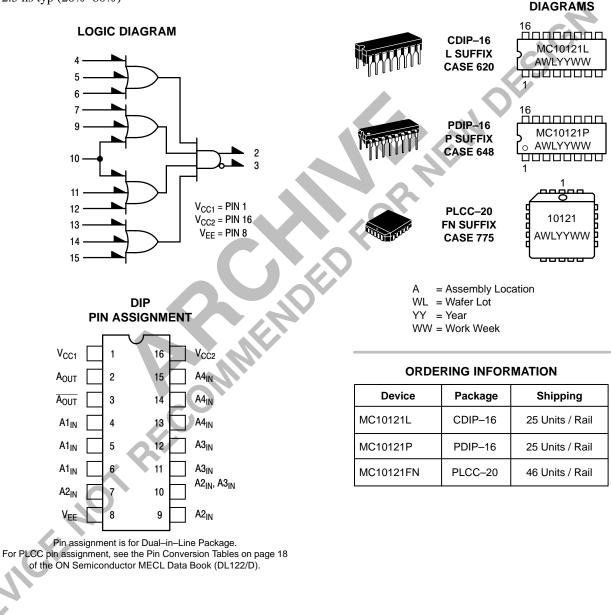
- $P_D = 100 \text{ mW typ/pkg}$ (No Load)
- $t_{pd} = 2.3$ ns typ
- $t_r, t_f = 2.5 \text{ ns typ} (20\%-80\%)$



ON Semiconductor

http://onsemi.com

MARKING



ELECTRICAL CHARACTERISTICS

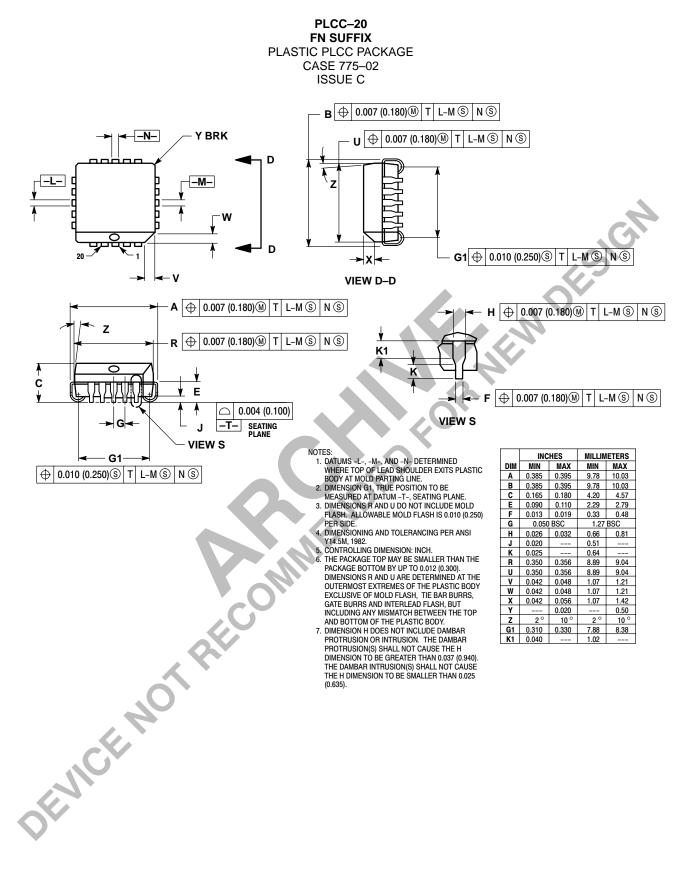
Characteristic Power Supply Drain Current Input Current Output Voltage Logic 1 Output Voltage Logic 0 Threshold Voltage Logic 1 Threshold Voltage Logic 0		Pin Under Test 8 7 9 10 7 9 10 7 9 10 3 2	Min 0.5 0.5 0.5	0° C <u>Max</u> 29 390 390 495	Min 0.5 0.5	+25°C Typ 20	Max 26 245 245 310	+85 Min 0.3	° C <u>Max</u> 29 245 245 310	Unit mAdo µAdo
Power Supply Drain Current Input Current Output Voltage Logic 1 Output Voltage Logic 0 Threshold Voltage Logic 1	I _E IinH IinL Vон	8 7 9 10 7 9 10 3	0.5 0.5 0.5	29 390 390	0.5		26 245 245		29 245 245	mAd μAdo
Input Current Output Voltage Logic 1 Output Voltage Logic 0 Threshold Voltage Logic 1	I _{inH} I _{inL} V _{OH}	7 9 10 7 9 10 3	0.5 0.5	390 390		20	245 245	0.3	245 245	μAdo
Output Voltage Logic 1 Output Voltage Logic 0 Threshold Voltage Logic 1	I _{inL} V _{OH}	9 10 7 9 10 3	0.5 0.5	390			245	0.3	245	
Output Voltage Logic 0 Threshold Voltage Logic 1	V _{OH}	10 7 9 10 3	0.5 0.5					0.3		
Output Voltage Logic 0 Threshold Voltage Logic 1	V _{OH}	9 10 3	0.5 0.5					0.3		
Output Voltage Logic 0 Threshold Voltage Logic 1	V _{OH}	10 3	0.5		0.5					μAdo
Output Voltage Logic 0 Threshold Voltage Logic 1		3			0.5			0.3		
Output Voltage Logic 0 Threshold Voltage Logic 1				0.000	0.5		0.040	0.3	0.700) (d a
Threshold Voltage Logic 1	V _{OL}		-1.060 -1.060	-0.890 -0.890	-0.960 -0.960		-0.810 -0.810	-0.890 -0.890	-0.700 -0.700	Vdc
		3	-1.890	-1.675	-1.850		-1.650	-1.825	-1.615	Vdc
		2	-1.890	-1.675	-1.850		-1.650	-1.825	-1.615	
Threshold Voltage Logic 0	V _{OHA}	3	-1.080		-0.980 -0.980			-0.910	6	Vdc
		2	-1.080	4.055	-0.980		4 620	-0.910	4 505	Vala
Threshold voltage Logic o	V _{OLA}	3 2		-1.655 -1.655			-1.630 -1.630		-1.595 -1.595	Vdc
Switching Times (50Ω Load)										ns
Propagation Delay	t ₄₊₃₋	3	1.4	3.6	1.4	2.3	3.4	1.4	3.5	
	t ₄₋₃₊	3	1.4	3.6	1.4	2.3	3.4	1.4	3.5	
	t ₄₊₂₊	2 2	1.4 1.4	3.6 3.6	1.4 1.4	2.3 2.3	3.4 3.4	1.4 1.4	3.5 3.5	
Rise Time (20 to 80%)	t ₄₋₂₋ t ₃₊	3	0.9	4.1	1.4	2.5	4.0	1.1	4.6	
(20 to 00 %)	t ₂₊	2	0.9	4.1	1.1	2.5	4.0	1.1	4.6	
Fall Time (20 to 80%)	t ₃₋	3	0.9	4.1	1.1	2.5 2.5	4.0	1.1 1.1	4.6	
DENICEN	STR	32								

ELECTRICAL CHARACTERISTICS (continued)

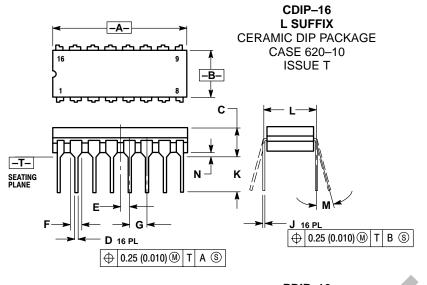
					TEST VOI	LTAGE VALU	JES (Volts)		
		@ Test Te	mperature	V _{IHmax}	V _{ILmin}	V _{IHAmin}	V _{ILAmax}	V _{EE}	
			–30°C	-0.890	-1.890	-1.205	-1.500	-5.2	
			+25°C	-0.810	-1.850	-1.105	-1.475	-5.2	
			+85°C	-0.700	-1.825	-1.035	-1.440	-5.2	
		Pin	TEST VOLTAGE APPLIED TO PINS LISTED BELOW						
Character	istic	Symbol	Under Test	V _{IHmax}	V _{ILmin}	V _{IHAmin}	V _{ILAmax}	V _{EE}	(V _{CC}) Gnd
Power Supply Drain Current		Ι _Ε	8					8	1, 16
Input Current		I _{inH}	7	7				8	1, 16
			9 10	9 10				8 8	1, 16 1, 16
		l _{inL}	7 9 10		7 9 10			8 8 8	1, 16 1, 16 1, 16
Output Voltage	Logic 1	V _{OH}	3 2	4, 10, 13				8	1, 16 1, 16
Output Voltage	Logic 0	V _{OL}	3 2	4, 10, 13				8 8	1, 16 1, 16
Threshold Voltage	Logic 1	V _{OHA}	3 2	10, 13		4	4	8 8	1, 16 1, 16
Threshold Voltage	Logic 0	V _{OLA}	3 2	10, 13		4	4	8 8	1, 16 1, 16
Switching Times	(50 Ω Load)			+1.11V		Pulse In	Pulse Out	–3.2 V	+2.0 V
Propagation Delay		t ₄₊₃₋ t ₄₋₃₊ t ₄₊₂₊ t ₄₋₂₋	3 3 2 2	10, 13 10, 13 10, 13 10, 13 10, 13		4 4 4 4	3 3 2 2	8 8 8 8	1, 16 1, 16 1, 16 1, 16 1, 16
Rise Time	(20 to 80%)	t ₃₊ t ₂₊	3 2	10, 13 10, 13		4 4	3 2	8 8	1, 16 1, 16
Fall Time	(20 to 80%)	t ₃₋ t ₂₋	3 2	10, 13 10, 13		4 4	3 2	8 8	1, 16 1, 16

Each MECL 10,000 series circuit has been designed to meet the dc specifications shown in the test table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 linear fpm is maintained. Outputs are terminated through a 50-ohm resistor to –2.0 volts. Test procedures are shown for only one gate. The other gates are tested in the same manner.

PACKAGE DIMENSIONS



PACKAGE DIMENSIONS



NOTES:

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
 DIMENSION L TO CENTER OF LEAD WHEN FOOMED DRAWLES

DIMENSION LTO CENTER OF LEAD WHEN FORMED PARALLEL.
 DIMENSION F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC BODY.

	INCHES		MILLIMETERS			
DIM	MIN	MAX	MIN	MAX		
Α	0.750	0.785	19.05	19.93		
В	0.240	0.295	6.10	7.49		
С		0.200		5.08		
D	0.015 0.020		0.39	0.50		
Е	0.050 BSC		1.27 BSC			
F	0.055	0.065	1.40	1.65		
G	0.100 BSC		2.54 BSC			
Н	0.008	0.015	0.21	0.38		
Κ	0.125	0.170	3.18	4.31		
L	0.300 BSC		7.62 BSC			
М	0 °	15 °	0 °	15°		
Ν	0.020	0.040	0.51	1.01		

-A-<u>ሳ ስ ስ ስ</u> 16 в 0 L $\Box \Box$ ι, հ - C S -T- SEATING PLANE H G **D** 16 PL

PDIP-16 **P SUFFIX** PLASTIC DIP PACKAGE CASE 648-08 ISSUE R

NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL. 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH. 5. ROUNDED CORNERS OPTIONAL

	INC	HES	MILLIMETERS		
DIM	MIN	MIN MAX		MAX	
Α	0.740 0.770		18.80	19.55	
В	0.250 0.270		6.35	6.85	
C	0.145	0.145 0.175		4.44	
D	0.015	0.015 0.021		0.53	
F	0.040	0.70	1.02	1.77	
G	0.100	BSC	2.54 BSC		
Н	0.050	BSC	1.27 BSC		
J	0.008	0.015	0.21	0.38	
K	0.110	0.130	2.80	3.30	
L	0.295	0.305	7.50	7.74	
Μ	0°	10 °	0 °	10 °	
S	0.020	0.040	0.51	1.01	

Notes

DEWICE NOT RECOMMENDED FOR MENDESIGN

Notes

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